

Transient Voltage Suppressor

Features

- Solid-state silicon-avalanche technology
- Low operating and clamping voltage
- Up to four I/O Lines of Protection
- Ultra low capacitance: 0.3pF typical(I/O to I/O)
- Low Leakage
- Low operating voltage:5V
- Flow-Through design

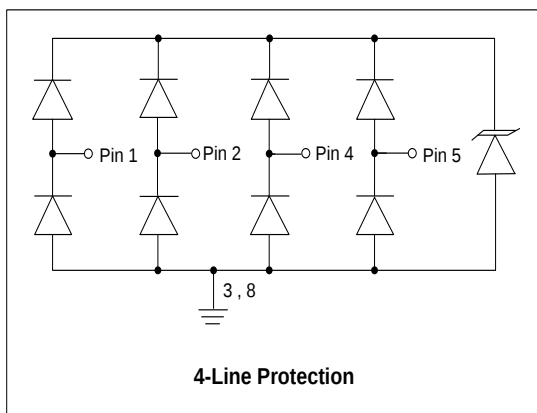
IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) $\pm 25\text{kV}$ (air), $\pm 22\text{kV}$ (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 4.5A (8/20 μs)

Mechanical Characteristics

- DFN-10L package (2.5 $\times$ 1.0 $\times$ 0.50mm)
- Marking: Marking Code
- Packaging: Tape and Reel
- RoHS Compliant

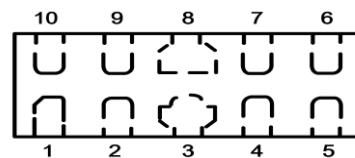
Circuit Diagram



Applications

- Digital Visual Interface(DVI)
- MDDI Ports
- DisplayPort TM Interface
- High Definition Multi-Media Interface(HDMI)

Schematic & PIN Configuration



Pin	Identificaion
1,2,4,5	Input Lines
6,7,9,10	Output Lines (No Internal Connection)
3,8	Ground

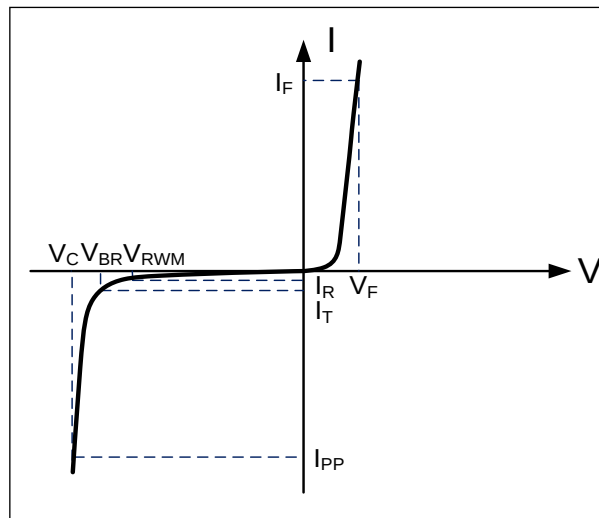
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Absolute Maximum Rating

Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	68	Watts
Peak Pulse Current ($t_p = 8/20\mu s$)	I_{PP}	4.5	A
Operating Temperature	T_J	-55 to + 125	°C
Storage Temperature	T_{STG}	-55 to + 150	°C

Electrical Parameters (T=25°C)

Symbol	Parameter
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Reverse Stand-Off Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_F	Forward Current
V_F	Forward Voltage @ I_F



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Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Stand-Off Voltage	V_{RWM}	Any I/O pin to ground			5	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	6			V
Reverse Leakage Current	I_R	$V_{RWM} = 5\text{V}$, $T=25^\circ\text{C}$ Any I/O pin to ground			500	nA
Clamping Voltage	V_C	$I_{pp}=1\text{A}$, $t_p=8/20\mu\text{s}$ Any I/O pin to ground			9	V
Clamping Voltage	V_C	$I_{pp}=4.5\text{A}$, $t_p=8/20\mu\text{s}$ Any I/O pin to ground			15	V
Dynamic Resistance ^{(1) (2)}	R_{DYN}	TLP=0.2/100ns		0.5		Ω
ESD Clamping Voltage ⁽¹⁾	V_C	$I_{PP} = 4\text{A}$ $t_p = 0.2/100\text{ns(TLP)}$		10		V
ESD Clamping Voltage ⁽¹⁾	V_C	$I_{PP} = 16\text{A}$ $t_p = 0.2/100\text{ns(TLP)}$		16		V
Junction Capacitance	C_j	$V_R = 0\text{V}$, $f = 1\text{MHz}$ I/O pin to GND			0.8	pF
		$V_{Pin3,8}=0\text{V}$ $V_R = 0\text{V}$, $f = 1\text{MHz}$ Between I/O pins		0.3	0.4	pF

Note1. TLP Setting: $t_p=100\text{ns}$, $t_r=0.2\text{ns}$, I_{TLP} and V_{TLP} sample window: $t_1=70\text{ns}$ to $t_2=90\text{ns}$.

Note2. Dynamic resistance calculated from $I_{PP}=4\text{A}$ to $I_{PP}=16\text{A}$ using "Best Fit".

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Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

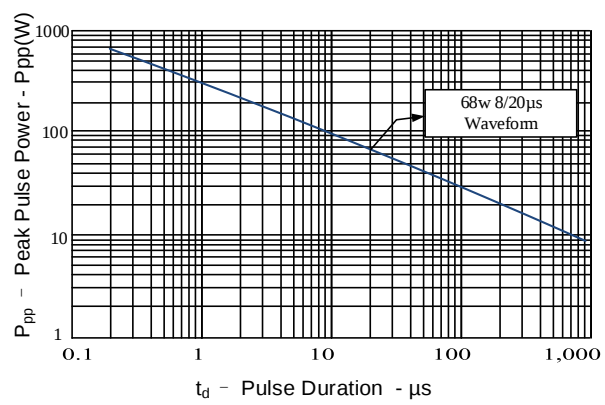


Figure 2: Power Derating Curve

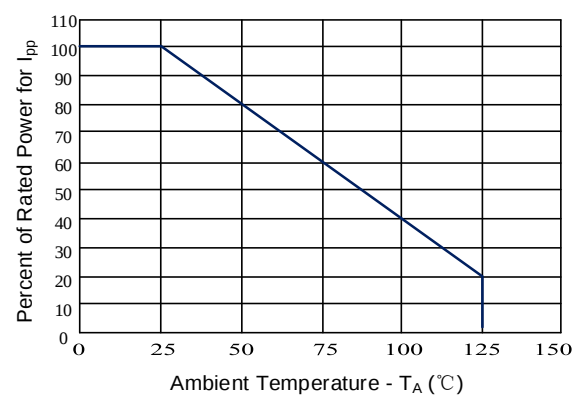


Figure 3: Clamping Voltage vs. Peak Pulse Current

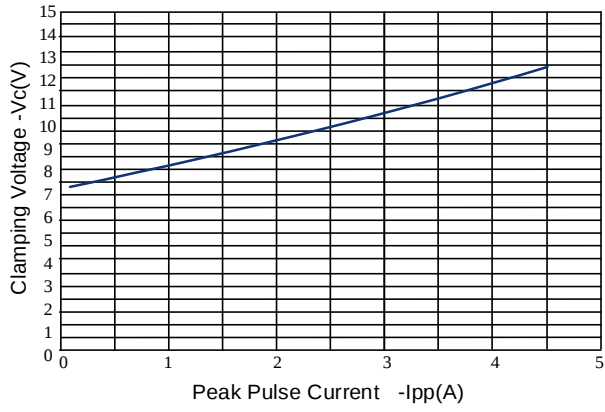


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

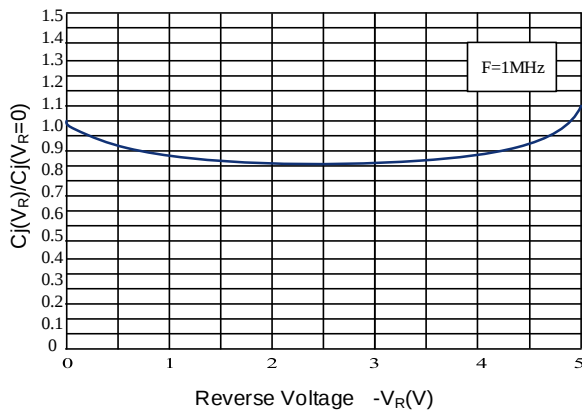


Figure 5: 8/20µs Pulse Waveform

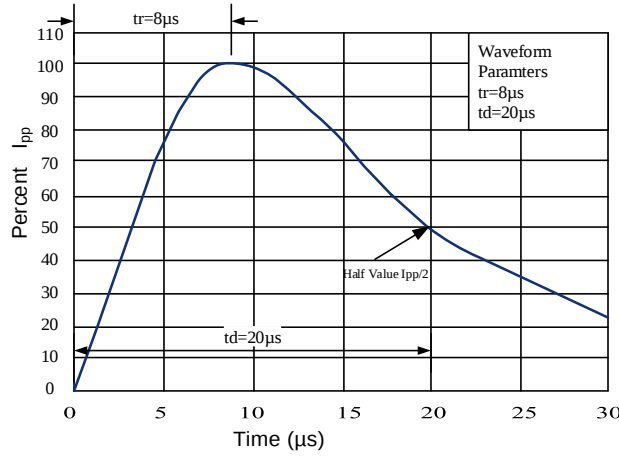
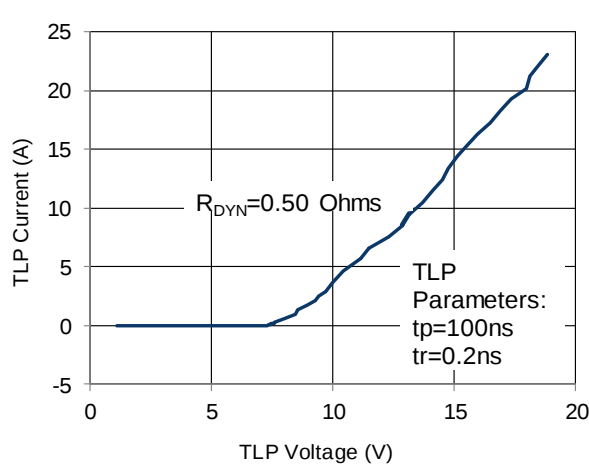


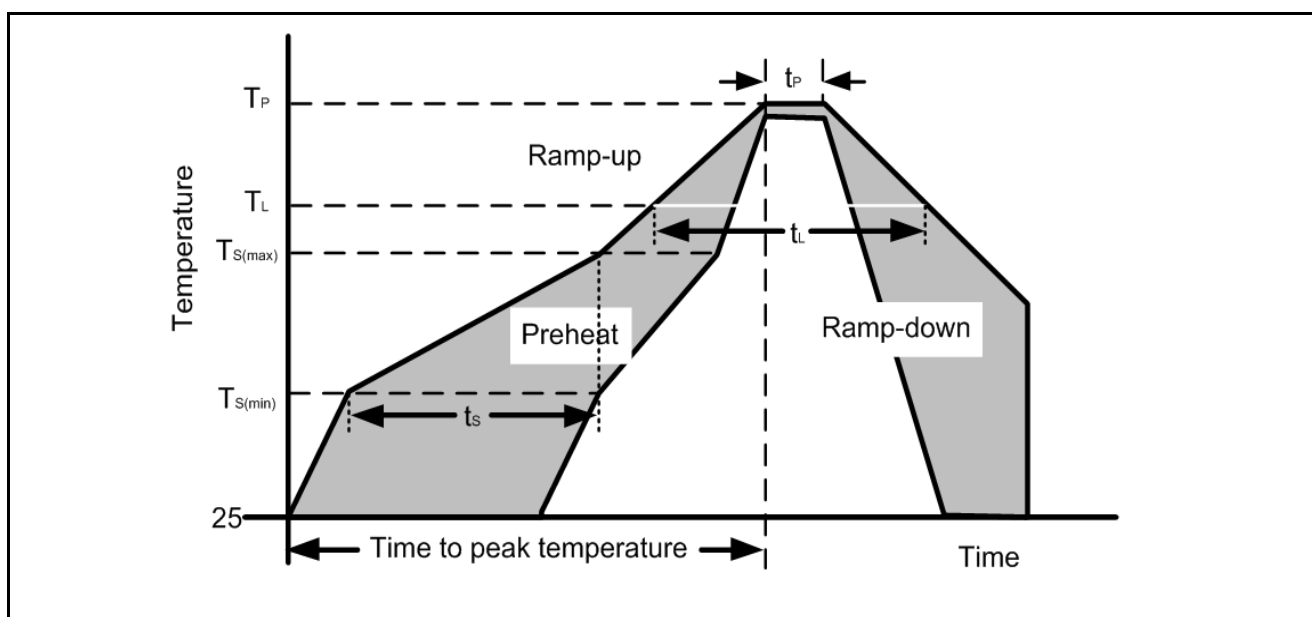
Figure 6: TLP I-V Curve



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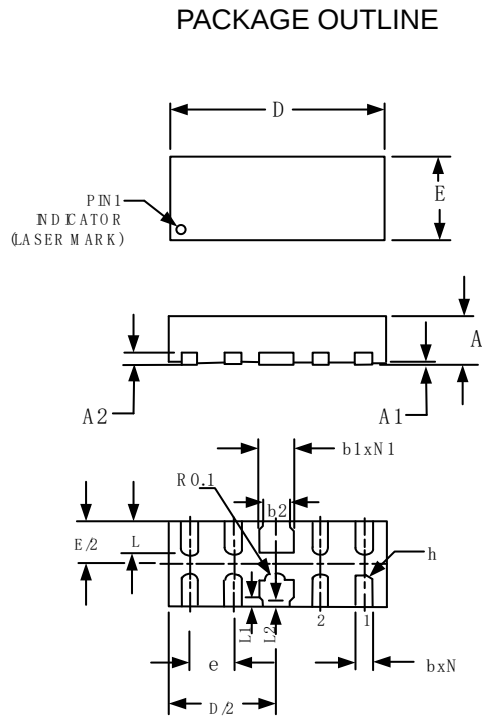
Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	Temperature Min ($T_{S(min)}$)	150°C
	Temperature Max ($T_{S(max)}$)	200°C
	Time (min to max) (t_s)	60 – 190 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L ——Ramp-up Rate		5°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_P)		260+0/-5 °C
Time within actual peak Temperature (t_P)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		280°C

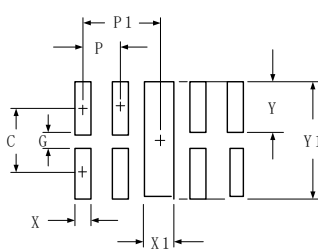


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Package Dimension-DFN2510-10L



SYMBOL	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.018	0.020	0.022	0.45	0.50	0.55
A1	0.000	0.001	0.002	0.00	0.02	0.05
A2	0.006			0.15		
b	0.006	0.008	0.010	0.15	0.20	0.25
b1	0.014	0.016	0.018	0.35	0.40	0.45
b2	0.008	0.010	0.018	0.20	0.25	0.45
D	0.096	0.098	0.100	2.45	2.50	2.55
E	0.037	0.039	0.041	0.95	1.00	1.05
e	0.020BSC			0.50BSC		
L	0.014	0.016	0.018	0.35	0.40	0.45
L1	0.000	0.003	0.004	0.00	0.075	0.10
L2	0.000	0.002	0.003	0.00	0.05	0.08
h	0.000	0.005	0.006	0.00	0.12	0.15
N	8			8		
N1	2			2		



DIMENSIONS		
DIM	INCHES	MILLIMETERS
C	0.034	0.875
G	0.008	0.20
P	0.020	0.50
P1	0.039	1.00
X	0.010	0.25
X1	0.018	0.45
Y	0.027	0.675
Y1	0.061	1.55

Notes:

Controlling Dimension: Millimeter.

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Ordering Information

Part	Package	Marking	Packing Information
ES054R2P	DFN2510-10L	5R2P	3k/Reel

Revision History and Checking Table

No.	Version	Date	Revision Item	Request	Function & Spec Checking	Package Checking	Tape Checking
1	1.0	2018-03-24	Released Version	Qi Shu Kun	Li Zi Hao	Liu Jia Ying	Liu Jia Ying